

产品规格书

SPECIFICATIONS FOR PRODUCT

产品类型 TYPE : SMD2520

产品规格 SPEC : 16MHz/2520/8PF/10PPM

产品型号 P/N : CJ15-160000810B20

日期 DATE : 2019/08/20

核准及签名			者βノブ
R&D APPR. SIGNATURED			DEPT.
拟制	审核	批准	频率器件事业部
ISSUE	СНЕСК	APPROVAL	
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JSCJ

JIANGSU CHANGJING ELECTRONICS TECHNOLOGY CO., LTD

SMCE2520 4pads Crystal Resonator

CJ15-160000810B20

1. Scope:

This specification applies to the RoHS/SONY compliance quartz crystal unit 1.1 with a frequency of 16MHz which will be used in crystal oscillator applications.

2. Construction:

2.1 Type of Quartz Resonator: SMCE2520 4pads

3. **Electrical Characteristics**

16.000MHz 3.1 Nominal Frequency(f):

8pF 3.2 Load Capacitance(C₁):

±10ppm 3.3 Frequency Tolerance($\triangle f/f$):

3.4 Frequency Temperature Stability:

100ohms Max 3.5 Resonance Resistance(ohm):

Fundamental mode

3.6 Osc mode:

3.7 Shunt Capacitance(C₀):

3.9 Operating Temperature Range(T_{OPR}):

3.10 Storage Temperature Range(T_{STG}):

3.11 Insulation Resistance(IR):

< 50µW 3.8 Drive Level(D₁):

-55 to + 125°C

>500 M ohms

± 3ppm per Year

3.12 Aging($\triangle f_A$):

1

±20ppm

<2pF

-40 to +85°C

4. Reliability Specifications

This is the quality control and quality assurance and reliability tests performance data for the RoHS/SONY compliance 16MHz SMCE2520 4pads crystal resonators

related to the specification and approval sheet provided by JSCJ .

Standard test condition (TEMP.: 20±5°C. Relative humidity: 65±20%)

For any discrepancy in GO/NG, test will be done at TEMP.25±2°C, R.H. 65±5%.

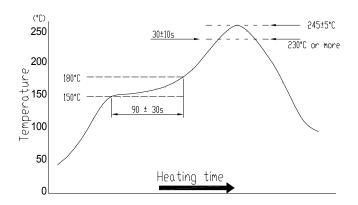
4.2 Lov (Gi Aa 4.3 Hig (Gi Ba 4.4 Hu	w Temperature Storage B/T 2423.1-2001, Method a) gh Temperature Storage B/T 2423.2-2001, Method a)	5ppm.Resonance resistance change after test ≤10ohms. Frequency change after test ≤± 5ppm.Resonance resistance change after test ≤10ohms. Frequency change after test ≤± 5ppm.Resonance resistance	10 cycles from -55°C to 125°C. Measurement taken after DUT being left at room temperature for 24±2 hours. Spending 72 hrs at -55°C±3°C constant temperature. Measurement taken after DUT being left at room temperature for 24±2 hours. Spending 72 hrs at 125°C±3°C constant
4.3 Hig (GI (GI Ba 4.4 Hu	B/T 2423.1-2001, Method a) gh Temperature Storage B/T 2423.2-2001, Method a)	5ppm.Resonance resistance change after test ≤10ohms. Frequency change after test ≤± 5ppm.Resonance resistance	temperature. Measurement taken after DUT being left at room temperature for 24±2 hours.
(GI Ba	B/T 2423.2-2001, Method	5ppm.Resonance resistance	Spending 72 hrs at 125°C±3°C constant
	umidity (GB/T 2423.3-	change after test ≤10ohms.	temperature. Measurement taken after DUT being left at room temperature for 24±2 hours.
		Frequency change after test ≤± 5ppm.Resonance resistance change after test ≤10ohms.	Spending 96 hrs at 40 °C \pm 3 °C, with 93 %R.H, Then keep the DUT in dry oven at 40 \pm 5 °C for 24 hour. Measurement taken after DUT being left at room temperature for 1 to 2 hours.
	95, Method Fc)	Frequency change after test ≤± 5ppm.Resonance resistance change after test ≤10ohms.	Apply 0.75mm vibration at sweep frequency $10\sim$ 500 Hz, 10 cycles in each direction of 3 axis. Measurement taken after 1 hour.
	ethod Ea)	5ppm.Resonance resistance	Peak 1000m/s2, normal width 6ms half sine wave form, 3.7m/s, 3 perpendicular axis of samples, 3 cycles / direction, total 18 cycles. Measurement taken after 1 hour.
	ethod Ed)	Frequency change after test ≤± 5ppm.Resonance resistance change after test ≤10ohms.and exhibit no visible damage.	Free drop to the steel plate with thickness of 3 mm from 1.00 m heights for 3 times.
1 1	, ` <u> </u>	Terminals shall be covered more then 95% with solder.	Passed through the re-flow oven under the following condition. Preheat 150 to 180°C for 60 to 120sec, and soldering time for 20s ± 5s at 235°C, peak soldering time for 10s ± 1s betweein 240 and 250°C. There is no need to do functional test. 8-12X magnifier.
	erminal Strength (JIS-C- 29 Method 1 & 2)	No visible damage	Mount on a glass-epoxy board (100x50x1.6mm), then bend to 2mm displacement (velocity 1mm/sec) and keep for 5 seconds. or pulling force 1.8kg for at least 60 seconds.
He	eat (IEC60068-2-58,Test	Frequency change after test ≤± 5ppm.Resonance resistance change after test ≤10ohms.	Passed through the re-flow oven under the following condition. Preheat 150 to 180°C for 60 to 120sec, and sodering time for 60s max at 235°C, peak soldering time for 20s max at 265°C max. Measurement taken after DUT being left at room temperature for at least 2 hours.
4.11 OT	THERS		

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5. Recommended Reflow soldering condition (SMD)

Solder profile

Peak: 245±5°C Soldering zone: 230°C or more, 30±10s. Pre-heating zone 1: 150 \sim 180°C, 90±30s



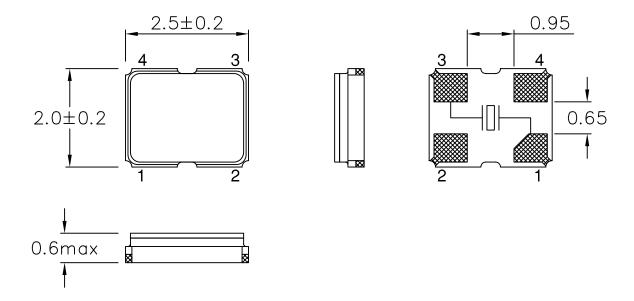
Temperature profile for reflow soldering

6. Soldering iron method

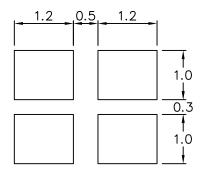
Bit temperature: $350\pm10^{\circ}$ C Application time of soldering iron:3+1 s. For other procedures, refer to IEC 60068-2-20.

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Package Outline Dimensions



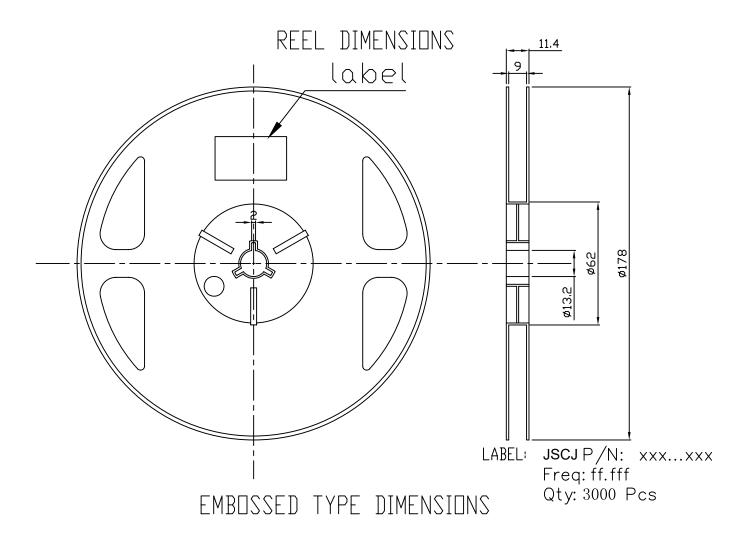
Suggested Pad Layout

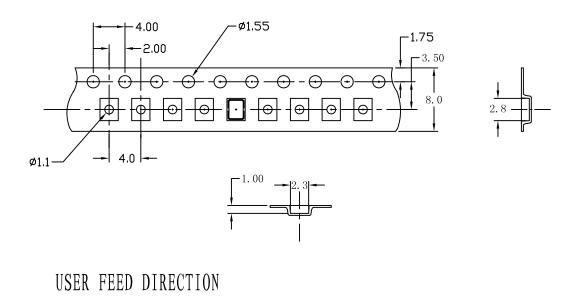


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